NSN 5962-01-047-6648

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View Online at https://aerobasegroup.com/nsn/5962-01-047-6648 **Body Length:** 0.808 inches **Body Width:** Between 0.220 inches and 0.294 inches **Body Height:** Between 0.139 inches and 0.204 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Radar set, type an/tps-43e **Features Provided:** Bipolar and hermetically sealed and high speed and monolithic and positive outputs and programmed and w/buffered output and w/decoded output and w/disable and w/enable and w/storage and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom **Memory Capacity:** Unknown **Test Data Document:** 97942-635a327 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life:

Demilitarization: Voc. domil/mli

Unit Of Measure:

N/a

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